

Voltage regulator diodes

PMLL5225B to PMLL5267B

FEATURES

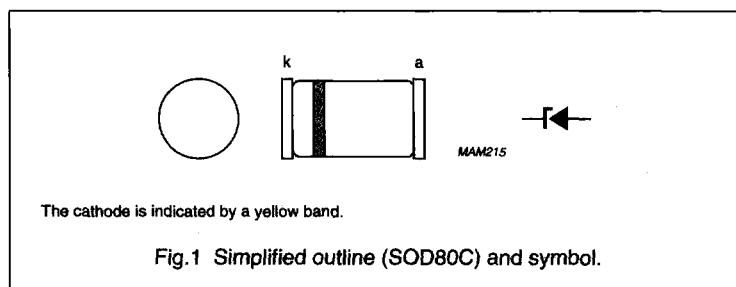
- Total power dissipation: max. 500 mW
- Tolerance series: $\pm 5\%$
- Working voltage range: nom. 3.0 to 75 V
- Non-repetitive peak reverse power dissipation: max. 40 W.

APPLICATIONS

- Low-power voltage stabilizers or voltage references.

DESCRIPTION

Low-power voltage regulator diodes in small hermetically sealed glass SOD80C SMD packages. The series consists of 43 types with nominal working voltages from 3.0 to 75 V.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_F	continuous forward current		–	250	mA
I_{ZSM}	non-repetitive peak reverse current	$t_p = 100 \mu\text{s}$; square wave; $T_J = 25 \text{ }^\circ\text{C}$ prior to surge	see Table "Per type"		
P_{tot}	total power dissipation	$T_{amb} = 25 \text{ }^\circ\text{C}$; note 1	–	500	mW
P_{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu\text{s}$; square wave; $T_J = 25 \text{ }^\circ\text{C}$ prior to surge; see Fig.3	–	40	W
		$t_p = 8.3 \text{ ms}$; square wave; $T_J \leq 55 \text{ }^\circ\text{C}$ prior to surge	–	10	W
T_{stg}	storage temperature		–65	+200	$^\circ\text{C}$
T_J	junction temperature		–65	+200	$^\circ\text{C}$

Note

1. If flanges are kept at $T_{flange} \leq 75 \text{ }^\circ\text{C}$.

ELECTRICAL CHARACTERISTICS

Total series

$T_J = 25 \text{ }^\circ\text{C}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_F	forward voltage	$I_F = 200 \text{ mA}$; see Fig.4	–	1.1	V

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Per type

 $T_j = 25\text{ }^\circ\text{C}$; unless otherwise specified.

TYPE No.	WORKING VOLTAGE V_z (V) ⁽¹⁾ at I_{ztest}	DIFFERENTIAL RESISTANCE r_{diff} (Ω) at I_{ztest}	TEMP. COEFF. S_z (%/K) at $I_z^{(2)}$	TEST CURRENT I_{ztest} (mA)	DIODE CAP. C_d (pF) at $f = 1\text{ MHz}$; at $V_R = 0\text{ V}$	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} (A) at $t_p = 100\text{ }\mu\text{s}$; $T_{amb} = 25\text{ }^\circ\text{C}$
	NOM.	MAX.	MAX.		MAX.	I_R (μA)	V_R (V)	MAX.
PMLL5225B	3.0	1600	-0.075	20	450	50	1.0	6.0
PMLL5226B	3.3	1600	-0.070	20	450	25	1.0	6.0
PMLL5227B	3.6	1700	-0.065	20	450	15	1.0	6.0
PMLL5228B	3.9	1900	-0.060	20	450	10	1.0	6.0
PMLL5229B	4.3	2000	± 0.055	20	450	5	1.0	6.0
PMLL5230B	4.7	1900	± 0.030	20	450	5	1.5	6.0
PMLL5231B	5.1	1600	± 0.030	20	300	5	2.0	6.0
PMLL5232B	5.6	1600	+0.036	20	300	5	3.0	6.0
PMLL5233B	6.0	1600	+0.036	20	300	5	3.5	6.0
PMLL5234B	6.2	1000	+0.045	20	200	5	4.0	6.0
PMLL5235B	6.8	750	+0.050	20	200	3	5.0	6.0
PMLL5236B	7.5	500	+0.058	20	150	3	6.0	4.0
PMLL5237B	8.2	500	+0.062	20	150	3	6.5	4.0
PMLL5238B	8.7	600	+0.065	20	150	3	6.5	3.5
PMLL5239B	9.1	600	+0.068	20	150	3	7.0	3.0
PMLL5240B	9.6	600	+0.075	20	90	3	8.0	3.0
PMLL5241B	11	600	+0.076	20	85	2	8.4	2.5
PMLL5242B	12	600	+0.077	20	85	1	9.1	2.5
PMLL5243B	13	600	+0.079	9.5	80	0.5	9.9	2.5
PMLL5244B	14	600	+0.082	9.0	80	0.1	10.0	2.0
PMLL5245B	15	600	+0.082	8.5	75	0.1	11.0	2.0
PMLL5246B	16	600	+0.083	7.8	75	0.1	12.0	1.5
PMLL5247B	17	600	+0.084	7.4	75	0.1	13.0	1.5
PMLL5248B	18	600	+0.085	7.0	70	0.1	14.0	1.5
PMLL5249B	19	600	+0.086	6.6	70	0.1	14.0	1.5
PMLL5250B	20	600	+0.086	6.2	60	0.1	15.0	1.5

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TYPE No.	WORKING VOLTAGE V_Z (V) ⁽¹⁾ at I_{Ztest}	DIFFERENTIAL RESISTANCE r_{diff} (Ω) at I_{Ztest}		TEMP. COEFF. S_z (%/K) at $I_Z^{(2)}$	TEST CURRENT I_{Ztest} (mA)	DIODE CAP. C_d (pF) at $f = 1$ MHz; at $V_R = 0$ V		REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} (A) at $t_p = 100$ μ s; $T_{amb} = 25$ °C
		NOM.	MAX.			MAX.	MAX.	I_R (μ A)	V_R (V)	
PMLL5251B	22		600	+0.087	5.6	60	0.1	17.0	1.25	
PMLL5252B	24		600	+0.088	5.2	55	0.1	18.0	1.25	
PMLL5253B	25		600	+0.089	5.0	55	0.1	19.0	1.25	
PMLL5254B	27		600	+0.090	4.6	50	0.1	21.0	1.0	
PMLL5255B	28		600	+0.091	4.5	50	0.1	21.0	1.0	
PMLL5256B	30		600	+0.091	4.2	50	0.1	23.0	1.0	
PMLL5257B	33		700	+0.092	3.8	45	0.1	25.0	0.9	
PMLL5258B	36		700	+0.093	3.4	45	0.1	27.0	0.8	
PMLL5259B	39		800	+0.094	3.2	45	0.1	30.0	0.7	
PMLL5260B	43		900	+0.095	3.0	40	0.1	33.0	0.6	
PMLL5261B	47		1000	+0.095	2.7	40	0.1	36.0	0.5	
PMLL5262B	51		1100	+0.096	2.5	40	0.1	39.0	0.4	
PMLL5263B	56		1300	+0.096	2.2	40	0.1	43.0	0.3	
PMLL5264B	60		1400	+0.097	2.1	40	0.1	46.0	0.3	
PMLL5265B	62		1400	+0.097	2.0	35	0.1	47.0	0.3	
PMLL5266B	68		1600	+0.097	1.8	35	0.1	52.0	0.25	
PMLL5267B	75		1700	+0.098	1.7	35	0.1	56.0	0.2	

Notes

1. V_Z is measured with device at thermal equilibrium while held in clips at 10 mm from body in still air at 25 °C.
2. For types PMLL5225B to PMLL5242B the I_Z current is 7.5 mA; for PMLL5243B and higher $I_Z = I_{Ztest}$. S_z values valid between 25 °C and 125 °C.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 10 mm	300	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length max.; see Fig.2 and note 1	380	K/W

Note

1. Device mounted on a printed circuit-board without metallization pad.

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GRAPHICAL DATA

